Piezoelectric coupling, phonons, and tunneling into a quantum Halledge

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We show that the piezoelectric coupling to three-dimensional phonons in GaAs renormalizes the current-voltage exponent for tunneling of electrons into an incompressible quantum Halledge. The leading correction is always negative, in agreement with experiments on the = 1=3 state and, depending on the precise value of the edge plasmon speed, can be as large as a few percent. We also discuss higher-order corrections, which determine the electrof the piezoelectric coupling in the extreme infrared limit.

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I. INTRODUCTION

The discrepancy between the tunneling exponent predicted by the conformal eld theory (CFT) of a quantum Hall (QH) edge and the one measured in cleavededge-overgrowth (CEO) experim ents^{2,3}, for a review see Ref. 4, remains a puzzle. For the principal lling frac-= 1=3, the discrepancy is not that large but is still believed to require an explanation (for recent discussions of the issue, see Refs. 5,6). A natural way to resolve the discrepancy would be to identify additional gapless modes, not present in the original chiral CFT. Such modes appear, for example, in scenarios based on the \edge reconstruction". 7,8 A nother group of explanations involves the role of the Coulomb interaction in the presence of a \hard " edge;9,10 pro les of the electron density obtained num erically in this case are rather similar to those resulting from edge reconstruction. Finally, although we do not address that case in the present paper, we note that there seems to be a discrepancy between theory and experim ent also for compressible QH states; for m ore detail, see Refs. 4,11.

The e ect of a one-dimensional (1D) \phononlike" mode on scattering between twoQH edges was considered in Ref. 12, and it was shown that a derivative coupling of the charge density to such a mode does renormalize the resistance. For tunneling from a bulk metal into a single edge, as in the CEO experiments, this coupling will similarly renormalize the tunneling exponent. The requisite 1D phononlike mode, propagating only along the edge, can be a result of the edge reconstruction or other mechanisms enumerated in Ref. 12, all of which have to do with the near-edge properties of the electron density.

For the purpose of explaining the experimental data, however, one does not have to consider the electronic system alone. In particular, in the present paper we note a hitherto apparently unidentied e ect of the ordinary three-dimensional (3D) acoustic phonons in GaAs. The derivative coupling of the type considered in Ref. 12 is irrelevant in this case, in the sense that it does not lead to a logarithm ic correction to the propagator of the edge plasmon. (The replacement of the 3D phonon with a 1D phonon in this problem in Ref. 13 looks to us completely arbitrary.) As we show here, however, there is a loga-

rithm ic e ect (and consequently a renorm alization of the tunneling exponent) due to the piezoelectric coupling.

We lim it ourselves to the principal lling fractions = 1 = (2p + 1) and assume that the CFT contains a single chiral boson | the left-moving edge plasmon mode. However, the phonon-induced correlation to which we attribute our results may also play a role in a much broader class of problems involving 1D conductors.

The piezoelectric electron-phonon interaction is described by the Hamiltonian

$$H_{piezo} = h@_{x L}$$
 (y) (z): (1)

Here $_{\rm L}$ is the chiral eld of the edge plasm on, $\frac{1}{2}$ $\theta_{\rm x~L}$ is the representation of the electron density in the edge CFT, is the phonon eld, and h is the coupling constant. The delta-functions restrict the coupling to one dimension, and indeed $_{\rm L}$ is a 1D eld; however, is fully three-dimensional.

The piezoelectric coupling is known to be highly anisotropic, but here we follow a common practice and use a direction average. The main result | a renormalization of the tunneling exponent | does not depend on this replacement. In fact, one could get rid of the averaging directly in the solution, Eq. (21) below, by bringing h^2 under the integral over k_2 (the transverse wavenum ber of the phonon eld) and supplying it with an angular dependence. This would not a ect the structure of the infrared-sensitive terms.

We keep in m ind that there are three polarizations of acoustic phonons (two transverse and one longitudinal), but in our calculation their contributions simply add up, so we will think of as representing just one of them. Interactions of the form (1) have been considered in a variety of problems concerning GaAs structures (for recent work, see Ref. 14) but, to our know ledge, not in connection with tunneling into a QH edge.

It is straightforward to count the powers of m om enta and see that the H am iltonian (1) allows for a logarithm ic correction to the propagator of $_{\rm L}$. W e can anticipate the nature of the e ect by noting that the H am iltonian gives rise to a non-local time-dependent \potential" between

electrons, which to the leading order in h2 has the form

$$U(x;) = \frac{h^2}{v_{ph}(x^2 + v_{ph}^2)}: \qquad (2)$$

Here $v_{\rm ph}$ is the phonon speed, and the Euclidean time. Since this \potential" is attractive, we expect that it will tend to conne the electron cloud near the tunneling site, thus leading to a decrease in the tunneling exponent.

W hat rem ains, then, is to compute, using the interaction H am iltonian (1), the coe cient of the logarithm, to see if the e ect can be large enough to be experimentally accessible. In Sect. III, we will see that it can. The precise answer depends on the ratio c = $v_{\rm ph}$ of the speed of the chiral mode to that of the phonon. For c in the range $10^5 \{10^6 \text{ cm/s}$, the leading (in h^2) correction to the tunneling exponent ranges from an accessible = 0.09 to an apparently unobservable = 0.003. The correction is always negative, in agreement with the experiments 2 , on the = 1=3 state. Higher-order corrections and the = 1 state are discussed in Sect. IV. Sect. V is a sum mary of the results.

II. THE MODEL AND THE PATH INTEGRAL

W e start with the Euclidean action that consists of three parts: the individual actions of the 1D chiralboson $_{\rm L}$ and the 3D phonon , and the interaction corresponding to the H am iltonian (1):

$$Z$$

$$S_{E} = S + S + d d^{3}xH_{piezo}:$$
 (3)

A term that describes tunneling of a single electron between a Ferm i-liquid and the Q H edge will be added later. In Eq. (3),

$$S = \begin{cases} d & dx [i@_{L} @_{x L} + c (@_{x L})^{2}]; \\ d & dx [i@_{x L} @_{x L} + c (@_{x L})^{2}]; \end{cases} (4)$$

$$S = \begin{cases} d & d^{3}x \frac{1}{2} @_{x L} & d^{3}x + \frac{1}{2} & d^{3}x & d^{3}x \end{cases} (6)$$

= 1=4 , and = it is the Euclidean time. We denote 1D integrations by dx, and 3D ones by d^3x . Our normalization of the eld $_{\rm L}$ is such that the expansion in terms of the canonically normalized creation and annihilation operators has the form

$$L = \frac{X}{k < 0} \frac{1}{2 k L} (b_k e^{i! t + ikx} + b_k^y e^{i! t ikx}) + zm.;$$
(6)

where L is the length of the edge, and zm .stands for the zero m odes. 1 In this norm alization, the ferm ion creation operator in the chiral CFT is

$$y = : \exp(\frac{1}{L}) : :$$
 (7)

The easiest way to obtain a path integral for the chiral eld $_{\rm L}$ is to separate it into the even and odd (with respect to x) components: $_{\rm L}$ = $_{\rm e}$ + $_{\rm o}$. If we consider $_{\rm e}$ as the canonical coordinate, then it follows from (4) that

$$p = 2 \, \ell_{x} \, \ell_{o}$$
 (8)

is the corresponding canonical momentum. The path-integral measure can be written as D $_{\rm e}{\rm D}\,{\rm p}$ or, since the Jacobian of transform ation from p to $_{\rm o}$ does not depend on the eld, equivalently as D $_{\rm e}{\rm D}$ $_{\rm o}$ = D $_{\rm L}$. Thus, the vacuum -to-vacuum amplitude in the presence of a current J (x;) can be written as

$$Z$$
 R Z $[J] = D_L e^{S_E + d_{dxJ_L}}$: (9)

We assume that tunneling occurs at isolated sites in purities, or tunneling centers, and in what follows consider just one such site, located at x=0. The tunneling term S_t is then

Z
$$S_t = const d [c(0;)^{y}(0;) + H c.];$$
 (10)

where the operator c(0;) destroys a spin-polarized Ferm i-liquid electron at point x=0. Treating S_t perturbatively, we can obtain the tunneling rate via a version of the optical theorem , from the two-point correlator of . The requisite correlator is given by Eq. (9) with a special choice of the current:

$$J(x;) = \frac{1}{2}[(x x_1)(x_1) (x_2)]; (11)$$

corresponding to insertion of a ferm ion at $x=x_1$, $=_1$ and rem oval of a ferm ion at $x=x_2$, $=_2$. For the present purposes, we only need to consider $x_1=x_2=0$, but the structure of the correlator is elucidated by taking general x_1 and x_2 , so we compute it for that more general case

Note that the correlator just de ned corresponds to the bosonic version of time ordering, $\$

$$G(x;) = h0 J_B [(x_2; 2)]^{y} (x_1; 1)] J_i;$$
 (12)

where $x = x_2$ x_1 ; $x_2 = x_2$ 1, and

$$T_{B} [A(_{2})B(_{1})] = (_{1})A(_{2})B(_{1}) + (_{1})A(_{2});$$
(13)

even though the exponentials (7) are in fact ferm ions. This is inconsequential since the correlator (12) does not occur as an internal line in any Feynm an diagram.

W e consider the case of zero tem perature, T=0. The optical theorem gives the tunneling rate per a unit interval of the biasing energy E>0 in terms of the analytical continuation of $G\left(x;\right)$ to real time. For tunneling into the edge, the rate is

$$\frac{dR}{dE} / N (E) Im [i dte^{iE} G (0; it+)];$$
 (14)

where N (E) is the density of states in the Ferm i-liquid. As indicated by the in nitesimal > 0, in Eq. (14) we need the values of the correlator just below the real-taxis. These can be obtained by analytically continuing the Euclidean G (x;) from > 0.

Because the theory (3) is Gaussian, the path integral (9) can be computed exactly:

$$Z[J] = \exp(\frac{1}{2}JGJ);$$
 (15)

where G is the full G reen function of the chiral boson $_{\rm L}$ [convolution integrals are in plied in the exponent of Eq. (15)]. In the absence of phonons, G can be replaced by the free G reen function

$$G_0(x;) = i \frac{Z}{2} \frac{d dk_x}{2} \frac{e^{i + ik_x x}}{k_x (ic k_x)};$$
 (16)

which to logarithm ic accuracy equals

$$G_{0}(x;) = \begin{cases} 8 & \ln \frac{L}{c + ix}; > 0; \\ \ln \frac{L}{c - ix}; < 0: \end{cases}$$
 (17)

L is an infrared cuto , any dependence on which will disappear when we use G_0 (in place of G) in Eq. (15).

At small E, where N (E) tends to a constant, Eq. (14) then becomes

$$\frac{dR}{dE} / \text{Im } [i \quad dte^{iEt} (it+) \quad] = \frac{1}{()} E^{1}; \quad (18)$$

where = 4 = 1. The rate at a xed biasing voltage V is

$$R = \int_{0}^{Z_{eV}} \frac{dR}{dE} dE / V : \qquad (19)$$

Thus, in the model without phonons, the tunneling exponent is = 1 = | the prediction of the chiral CFT.

III. CORRECTION TO THE TUNNELING EXPONENT

We are interested in corrections to the results (18) and (19) due to the piezoelectric coupling (1). The full Green function G of the chiral boson is given by the following Fourier transform

$$G(x;) = \frac{Z}{\frac{d dk_x}{(2)^2}} e^{\frac{i}{1 + ik_x} x} F(;k_x); \qquad (20)$$

w here

$$F^{-1} = 2 k_x (i + c k_x) h^2 k_x^2 \frac{Z}{(2)^2} \frac{d^2 k_?}{(2)^2} \frac{1}{z^2 + v_{ph}^2 k^2};$$

 $k_?=(k_y;k_z)$, and $k^2=k_x^2+k_?^2$. Note that it is the coe cient of in in the boson G reen function (at x=0)

that determ ines the tunneling exponent $\,$. Consequently, we are interested in logarithm ic contributions to G $\,$

Form ally, Eq. (20) is the exact solution to our problem . However, it is not easy to analyze. A Itematively, it can be used to obtain a perturbative expansion of G, i.e., an expansion in powers of h^2 :

$$G(x;) = G_0(x;) + G_1(x;) + ::::$$
 (22)

The leading term is the free propagator (16), and the next-to-leading term equals

$$G_1(x;) = \frac{h^2}{4^2} \frac{Z}{(2)^4} \frac{d^3kd}{(2)^4} \frac{e^{\frac{1}{2} + ik_x x}}{(i - ic k_x)^2 (v_{ph}^2 k^2 + \frac{2}{2})}$$
:

Since the coupling h^2 is relatively small, we rst concentrate on this term; e ects of the higher-order corrections are discussed in the next section.

W riting

$$G_1(x;) = \frac{h^2}{16^{-2} v_{nh}^2} I(x;);$$
 (24)

we nd three types of logarithm ic terms in the integral $I: I = I_1 + I_2 + I_3$; for > 0

$$\begin{split} & I_1 \ = \ \frac{c}{c \ + \ ix} \ln [\ (c \ + \ ix)]; \\ & I_2 \ = \ \frac{c}{v_{ph}^2 \ \hat{c}} \ln \frac{L}{c \ + \ ix}; \\ & I_3 \ = \ \frac{1}{2} \sum_{s=-1}^{X} \frac{1}{v_{ph} + sc} \ln \frac{L}{v_{ph}} \frac{L}{isx}; \end{split}$$

is the ultraviolet (m om entum) cuto . The approximate sign in the expression for I m eans that only term s that give rise to \ln are kept.

Setting x = 0, we obtain, to logarithm ic accuracy

$$G_1(x;) = \frac{h^2 ^2}{v_{nh} c (v_{nh} + c)} \ln :$$
 (25)

The corresponding correction to the tunneling exponent is

$$= \frac{2h^2}{v_{ph}c (v_{ph} + c)}; \qquad (26)$$

where the factor of 2 is due to the presence of two transverse polarizations of the phonon (the third, longitudinal, polarization has larger velocity and gives a smaller contribution). Note that the correction is always negative.

For estim ates, we use the same expression for the piezoelectric coupling and the same values of the parameters as in Ref. 14. In our present notation,

$$h^2 = \frac{1}{h_M} \frac{ee_{14}}{4}$$
 (27)

where $_{\rm M}$ = 5:36 g/cm 3 , ${\rm e}_{14}$ = 0:16 C/m 2 , and = 13.2 $_{0}$; in this equation only, we have restored h. W ith

these num bers, $h^2 = 5:39$ 10^6 m $^3/s^3$. U sing also $v_{ph} = 3000$ m/s, we can rewrite Eq. (26) as a function of a single parameter, the ratio

$$r = c = v_{ph}$$
: (28)

W e obtain

$$= \frac{0.04}{r(1+r)} : (29)$$

C learly, the smaller is r the larger is the correction. While for $c=10^4$ m/s it is only 0.003 in the absolute value, for $c=10^3$ m/s it is already 0.09. The latter number is roughly of the same order of magnitude as the discrepancy between the CFT prediction = 3 for = 1=3 and the central values = $2.65\{2.85$ obtained experimentally^{2,3} for dierent samples. This number is also larger than the experimental uncertainty quoted for the experiment of Ref. 2.

The most obvious way to experimentally test the present theory is to reduce the plasm on speed via a capacitive coupling to external conductors. In that case, Eq. (29) predicts a further decrease in . This prediction, however, holds only insofar as corrections of higher orders in h^2 can be neglected, cf. the next section.

IV. HIGHER-ORDER CORRECTIONS

Expanding the exact Fourier transform (21) in powers of h^2 , we obtain higher-order corrections to the plasm on G reen function. In this section, we consider the structure of the perturbation series for the case c $$v_{\rm ph}$$, which is the sim plest. In this case, the main contribution to G in a given order can be found by dropping 2 in the integral over k_2 . The nth-order correction to the G reen function at \$>0\$ becomes

$$\text{G}_{\text{n}} \text{ (x;)} \quad \frac{h^2}{\text{n!}} \quad \frac{h^2}{v_{\text{ph}}^2} \quad \ \ _0 \, \text{dk}_{\text{x}} \, k_{\text{x}}^{\text{n}} \quad ^1 \text{e} \quad ^{\text{(c} \quad + \, \text{ix} \,)} k_{\text{x}} \, \ln^{\text{n}} \frac{}{k_{\text{x}}} :$$

At x=0 all these terms are positive, so their sum remains the main contribution to the sum of the entire perturbation series.

From now on we concentrate on x=0. It turns out that the sum of (30) over n saturates at values of n that are much smaller than $n_0 = c$. For such n, the logarithm in (30) can be considered a slow ly varying function of k_x , so that (for $n \in 0$)

$$G_n(x;) = \frac{h^2}{n} \frac{!_n}{v_{ph}^2 c} \cdot h^n \frac{n_0}{n} - \frac{n}{n} \cdot h^n \frac{n_0}{n} : (31)$$

The last equality de nes the dimensionless coupling .

It is som ewhat more convenient to consider, instead of the sum of $G_{\,\mathrm{n}}$, the sum of their derivatives with respect

to n_0 . Thus, if we denote by G the full correction to the G reen function, G = G G_0 , then

$$\frac{\text{@ G}}{\text{@n_0}} = \frac{X^{n_0}}{n_0} \prod_{n=1}^{n_0} \ln^{n_0} \frac{1}{n} : \tag{32}$$

If n is regarded as a continuous variable, the expression under the sum has a maximum at n=n , where

$$n = n_0 e^{\frac{1}{n}} [1 + O(\frac{1}{n}) + O()];$$
 (33)

We de ne a characteristic time 0 by

$$_{0}^{1} = c \exp(\frac{v_{ph}^{2}C}{h^{2}} - 1)$$
: (34)

Eq. (33) can now be written $\sin p \ln x$ as n = 0. We see that 0 is the infrared scale at which the perturbation theory breaks down. At 0, the sum over n is essentially discrete and is well-approximated by the lowest-order term. On the other hand, if is signicantly larger than 0, many terms contribute. In that case, n is indeed quasi-continuous.

At even larger times, $_{0}\text{=}$, the steepest descent condition becomes applicable near n = n , and using steepest descent we obtain

$$\frac{\text{@ G}}{\text{@ n_0}} = \frac{1}{n_0} (2 \text{ n})^{1=2} \exp\left[-\frac{1}{n_0} + 0 \text{ (n)}^2\right] : \quad (35)$$

The exponential growth of Eq. (35) at large indicates the presence of a plasm on state with energy

$$E_{p} = \frac{h^{2}}{V_{ph}^{2}C_{0}} : (36)$$

The same conclusion can be reached by looking directly at the resum med expression (21) or, more precisely, its real-time version obtained by replacing with i!. (In the presence of a state with a negative energy, the rotation to Euclidean frequencies needs to be rede ned.) Neglecting again the frequency dependence of the integral over $k_{\rm P}$, we see that the interaction shifts the pole of F from ! = c $k_{\rm x}$ to ! = f $(k_{\rm x})$, where

$$f(k_x) = c k_x (1 ln_{\overline{k_x}}):$$
 (37)

This function has extrem a at $k_x = (c_0)^1$, where it equals E_p j.

We interpret the presence of plasm on states with negative energies as a rejection of the polaron eject formation of a bound state of an electron and the phonon eld. This interpretation is supported by the following estimate. Suppose we qualitatively describe the cumulative eject of the attractive interaction (2) over time by the time-independent potential

$$\vec{v}(x) =$$
 $\vec{v}(x) = \frac{1}{v_{\text{ph}}^2 \dot{x} \dot{y}} :$
(38)

For an electron cloud with density distribution n (x) and spatial size of order of the \correlation length" c $_{0}$, the binding energy can then be estimated as

$$E_e = \frac{1}{2}^{Z} dxdyn(x)U'(x y)n(y) \frac{h^2 \ln(c_0)}{v_{ph}^2 c_0}$$
: (39)

An electron cloud can be thought of as containing of order (l=) \ln (c $_0$) plasm ons (in the sense that this is how many plasm ons are typically produced when an electron-hole pair annihilates). D ividing Eq. (39) by this number, we obtain an estimate of energy per plasm on in agreement with Eq. (36).

A corollary to this argum ent is that any infrared e ects associated with production of plasm one should saturate at time scales of order $_{0}$ (equivalently, length scales of order c $_{0}$, the size of the polaron). We therefore expect that in the extreme infrared, at biasing energies

$$E \qquad \mathcal{E}_{e} j \qquad \frac{1}{0} ; \qquad (40)$$

the system , at any $\,$, will cross over to the norm alFerm iliquid behavior.

We now estimate the timescale $_0$ for = 1=3 and = 1. The maximal phonon momentum is $= !_D = v_{\rm ph}$, where $!_D$ is the Debye frequency; for GaAs, $!_D = 345~{\rm K}$. 15 G iven the uncertainty introduced by the directional averaging of hand by the imprecise know ledge of $= c = v_{\rm ph}$, we prefer to extract the entire combination $y = h^2 = v_{\rm ph}^2$, occurring in Eq. (34), directly from the experimentally measured values of the tunneling exponent. In the limit $c = v_{\rm ph}$, the lowest order correction (26) is simply = 2y. Assuming (and con ming a posteriori) that the perturbation theory works well for

the = 1=3 state, we nd that, e.g., the sam ple^2 with = 2:7 corresponds to y = 0:15. For = 1=3, Eq. (34) then gives $_0$ 1 10 9 r! $_D$, which is unobservably small. We conclude that for = 1=3, in the experimentally relevant range of voltages and temperatures, the low est-order result (26) is reliable.

The situation is quite di erent for = 1. Using the same value of y, we now obtain $_0^{-1} = 14r$ eV, close to the observable range of energies. The lowest-order result (26) predicts a negative correction to the tunneling exponent at = 1. Experimentally, no such negative correction has been observed. 2,16 W e see that this may be related to the breakdown of the perturbation theory for = 1.

V. CONCLUSION

We have computed the leading correction Eq. (26)], due to the piezoelectric coupling to 3D phonons, to the current-voltage exponent for tunneling between a Ferm i-liquid and a=1=(2p+1) QH edge. The correction is always negative, in agreement with the experiments^{2,3} on the =1=3 state, and its magnitude depends on the value of the edge plasm on speed.

We have also shown that, in the experimentally relevant range of energies, higher-order corrections for = 1=3 are small and do not invalidate the leading-order result, but for = 1 they very well might. In neither case, however, the leading-order result (26) represents the true infrared behavior: at a su ciently low energy, higher-order e ects will always become important.

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